



*ITW*

PATENT  
Customer No. 22,852  
Attorney Docket No. 04329.3140

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:	)	
	)	
Takashi YODA et al.	)	Group Art Unit: 2814
	)	
Application No.: 10/663,799	)	Examiner: Cao, Phat X.
	)	
Filed: September 17, 2003	)	Confirmation No. 3768
	)	
For: SEMICONDUCTOR DEVICE	)	
WITH POROUS LAYER AND	)	
CONDUCTIVE BARRIER LAYER	)	
(AS AMENDED)	)	

**Mail Stop Amendment**  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

**AMENDMENT**

In reply to the Office Action mailed January 11, 2005, the period for response to which extends through April 11, 2005, please amend the application as follows.

**An Amendment to the Title** is set forth on page 2 of this paper.

**Amendments to the Claims** are reflected in the listing of claims beginning on page 3 of this paper.

**Remarks** begin on page 9 of this paper.

**AMENDMENT TO THE TITLE:**

Please amend the title of this application as follows:

SEMICONDUCTOR DEVICE ~~AND METHOD OF MANUFACTURING THE SAME~~  
WITH POROUS LAYER AND CONDUCTIVE BARRIER LAYER